



JOCSZ21X,JOCSZ31X-D6P/S Series

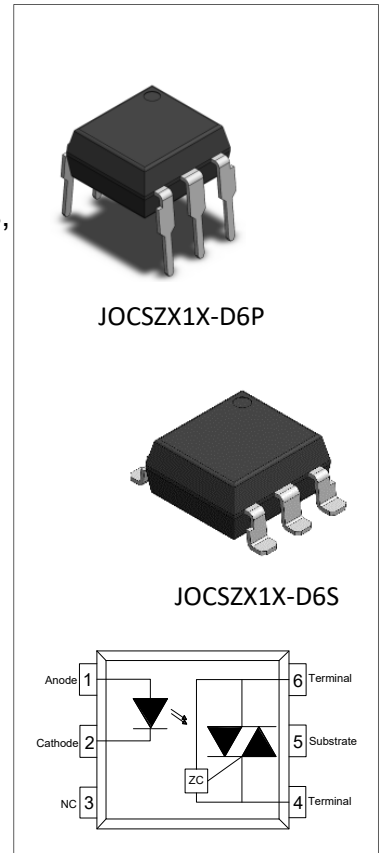
Rev.A.1.0

DESCRIPTION:

The products are 6-pin thyristor opto-couplers. The device combines an AlGaAs infrared emitting diode as the emitter which is optically coupled to a monolithic silicon zero-crossing photo triac in a plastic DIP6 package with different lead forming options. The products are widely used in solenoid/valve controls, lighting controls, motor controls, temperature controls, static AC power switches, solid state relays, interfacing microprocessors up to 265 V_{AC} peripherals.

MAIN FEATURES

- High isolation 5000 VRMS
- DC input with zero-crossing photo triac output
- Operating temperature range -55 °C to 110 °C
- REACH & RoHS compliance
- HBM: H3A; MM: M4; CDM: C3
- CQC approved
- VDE approved
- UL approved



ABSOLUTE MAXIMUM RATINGS (Temperature=25°C)

Parameter		Symbol	Value	Unit	
Input	Forward Current	I _F	50	mA	
	Peak Forward Current	I _{FP}	1 ^①	A	
	Reverse Voltage	V _R	6	V	
	Power Dissipation	P _D	75	mW	
Output	Off-state Output Terminal Voltage	V _{OFF}	JOCSZ21X	600	V
			JOCSZ31X	800	
	Peak On-state Current (100μs pulse, 120 pps)	I _{TP}	2	A	
	On-state RMS Current	I _{T(RMS)}	100	mA	
	Peak Repetitive Surge Current (P _w =10 ms)	I _{TSM}	1.2	A	
Output Power Dissipation		P _O	250	mW	
Total Power Dissipation		P _{tot}	325	mW	
Isolation Voltage		V _{iso}	5000 ^②	Vrms	

Operating Temperature	T_{opr}	-55~110	°C
Junction Temperature	T_j	125	°C
Storage Temperature	T_{stg}	-55~125	°C
Soldering Temperature	T_{sol}	260	°C
Peak pulse voltage ($T_j=25^{\circ}C$; non-repetitive,off-state)	V_{pp}	1	kV

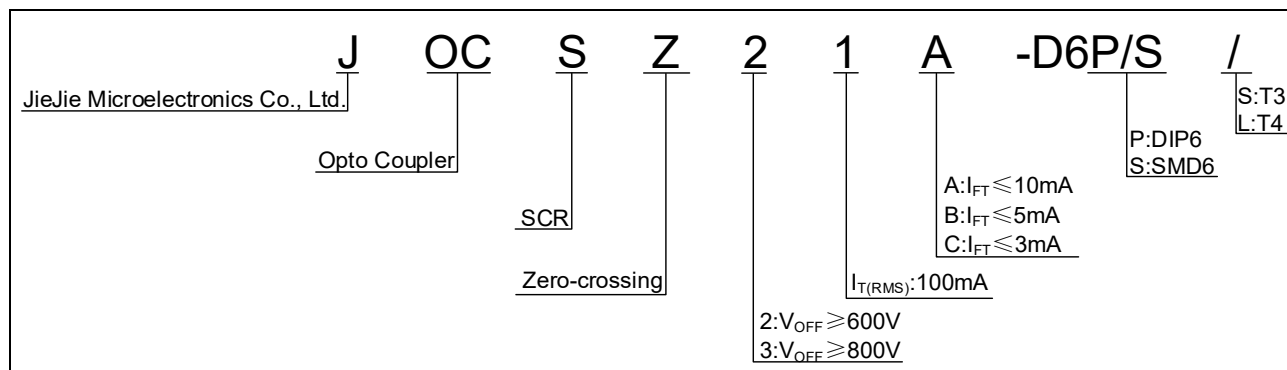
NOTE1: 100μs pulse, 100Hz frequency **NOTE2:** AC for 1minute, R.H.=40~60%

ELECTRICAL CHARACTERISTICS (Temperature=25°C)

Parameter		Symbol	Condition	Min.	Typ.	Max.	Unit
Input	Forward Voltage	V_F	$I_F=10mA$	-	1.2	1.5	V
	Reverse Current	I_R	$V_R=6V$	-	-	1	μA
	Input Capacitance	C_{in}	$V=0, f=1kHz$	-	10	-	pF
Output	Peak Off-state Current, Either Direction	I_{OFF}	$V_{OFF}=Rated V_{OFF}$ $I_F=0$	-	-	100 ^③	nA
	Peak On-state Voltage, Either Direction	V_{TM}	$I_{TM}=100mA$	-	1.7	2.5	V
	Critical Rate of Rise of Off-state voltage	dV/dt	$V_{PEAK}= Rated V_{PEAK}$ $I_F=0$	2000 ^④	-	-	V/μs
Transfer Characteristics	LED Trigger Current	JOCSZ21A JOCSZ31A	Terminal Voltage=3V $I_{TM}=100mA$	-	-	10	mA
		JOCSZ21B JOCSZ31B		-	-	5	
		JOCSZ21C JOCSZ31C		-	-	3	
	Holding Current	I_H	$I_{TM}=2mA,$ $I_F=Rated I_{FT}$	-	500	-	μA
	Isolation Resistance	R_{ISO}	DC500V 40~60%R.H.	10^{12}	10^{14}	-	Ω
	Floating Capacitance	C_{IO}	$V=0,$ $f=1MHz$	-	10	-	pF
	Response Time	t_{on}	$V_D=6V,$ $R_L=100\Omega,$ $I_F=20mA$	-	15	50	μs
Zero-crossing Characteristics	Inhibit Voltage	V_{IH}	$I_F=Rated I_{FT}$	-	-	20	V
	Leakage in Inhibited State	I_{OFF2}	$I_F=Rated I_{FT},$ $V_{OFF}=Rated V_{OFF}$	-	-	1.5	mA

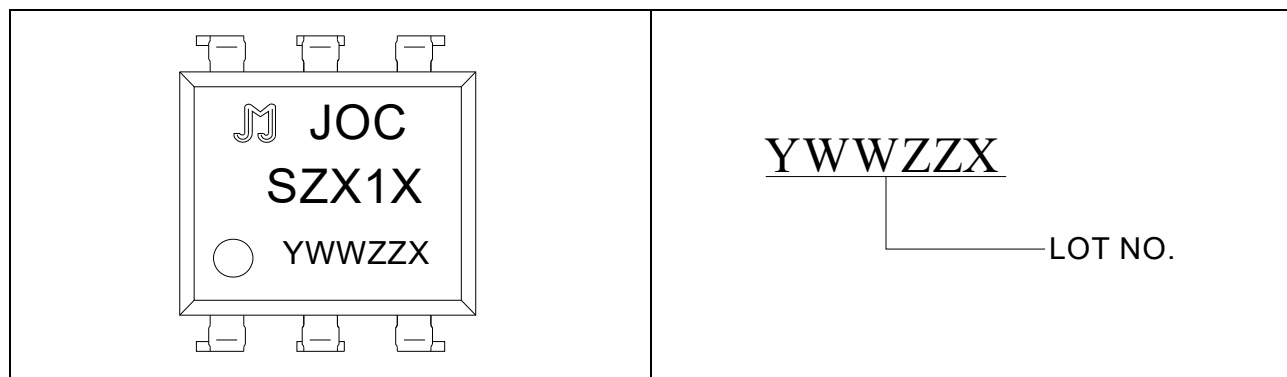
NOTE3: Test voltage must be applied within dV/dt ratings. **NOTE4:** Refer to Fig.14 & Fig.15

ORDERING INFORMATION



Packing Quantity	
Option	Quantity
DIP	60 Units/Tube
SMD	1200 Units/Reel

MARKING



Characteristics Curves

FIG.1: Max. Allowable LED Forward Current vs. Ambient Temperature

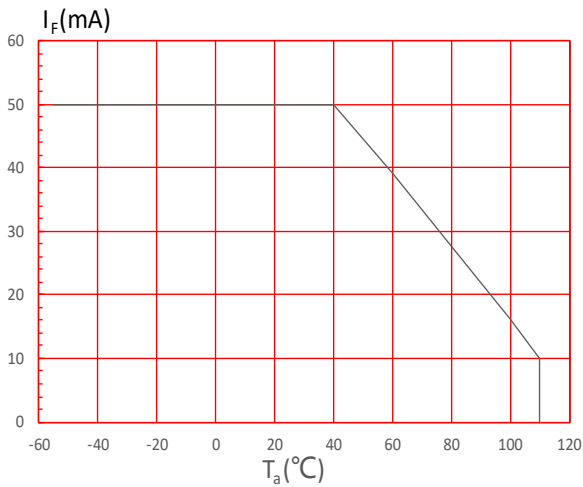


FIG.2: On-state Terminal Current vs. Ambient Temperature

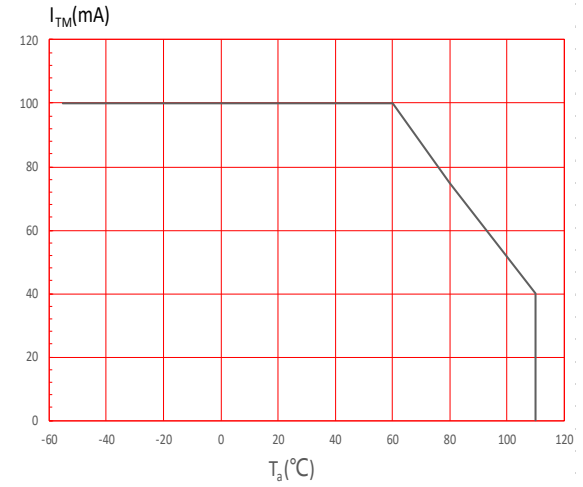


FIG.3: Forward Current vs. Forward Voltage

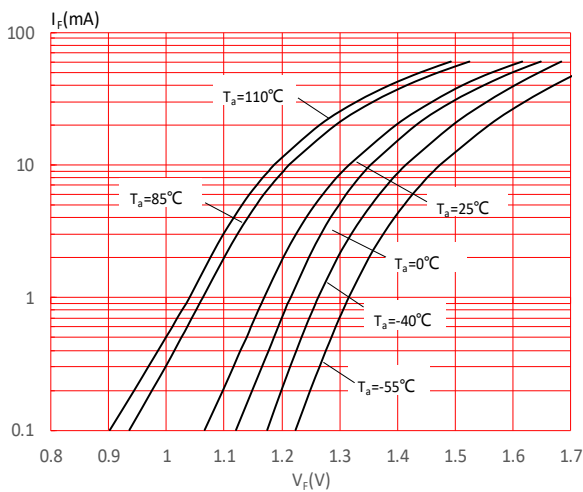


FIG.4: Normalized Off-state Terminal Current vs. Ambient Temperature

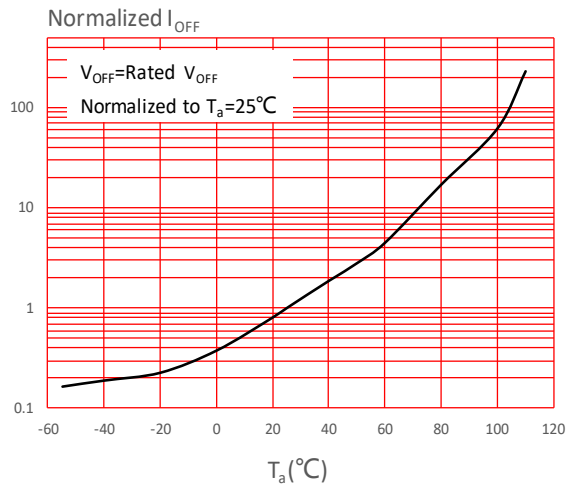


FIG.5: Normalized Off-state Terminal Voltage vs. Ambient Temperature

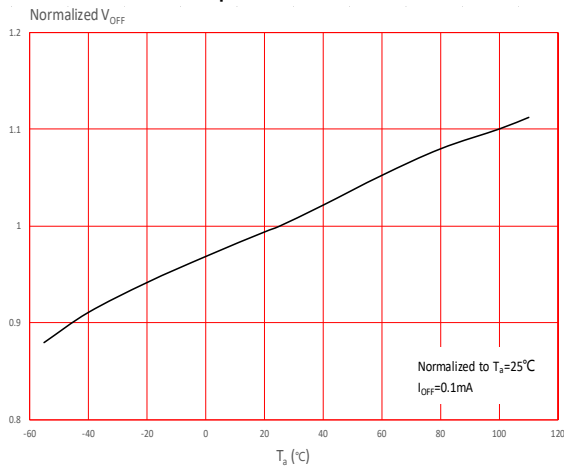


FIG.6: Normalized Trigger Current vs. Ambient Temperature

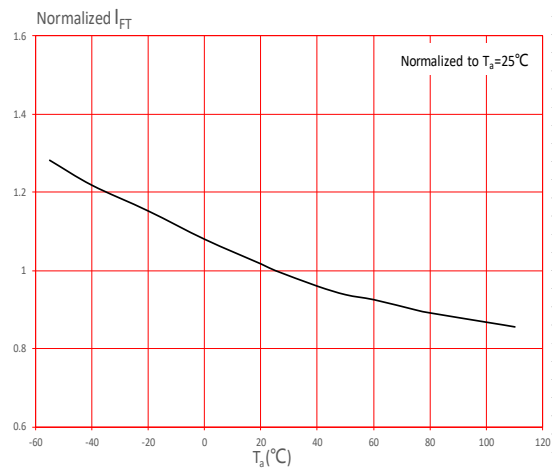


FIG.7: Normalized On-state Terminal Voltage vs. Ambient Temperature

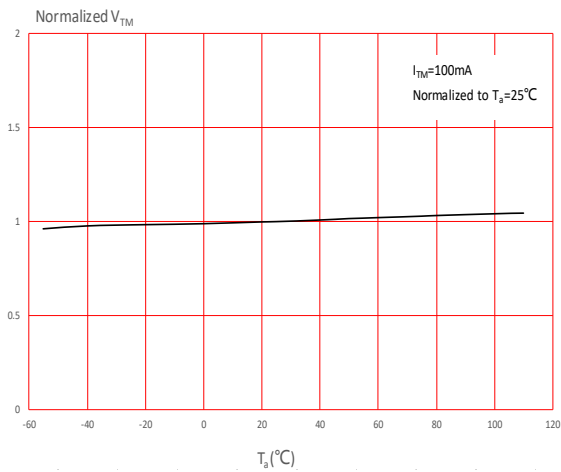


FIG.8: On-state Terminal Voltage vs. On-state Terminal Current

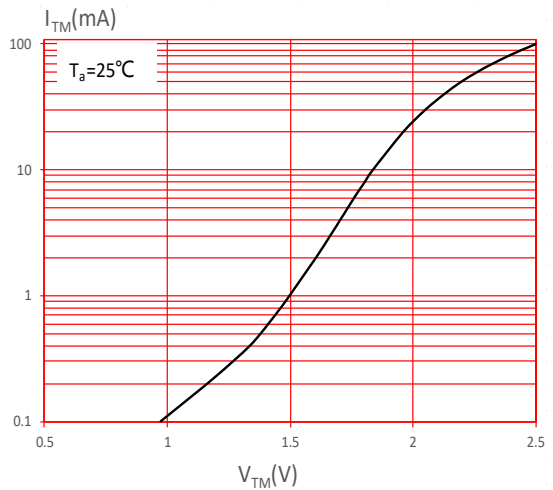


FIG.9: Normalized Holding Current vs. Ambient Temperature

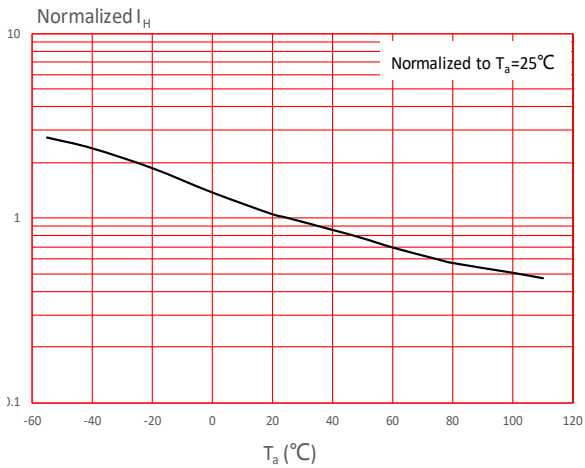


FIG.10: Normalized Leakage in Inhibit State vs. Ambient Temperature

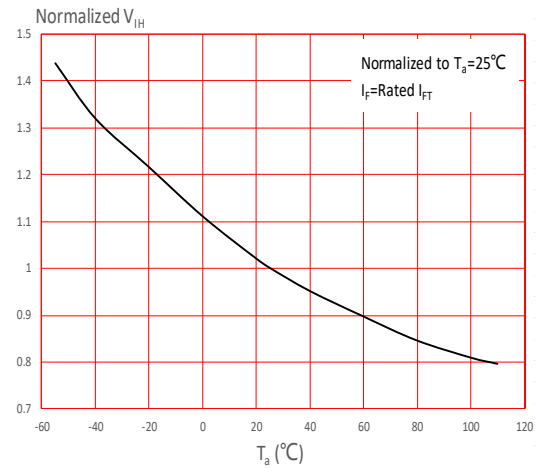
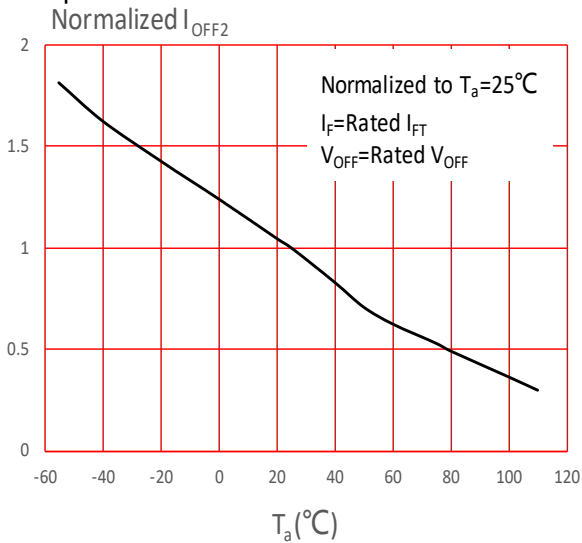


FIG.11: Normalized Inhibit Voltage vs. Ambient Temperature



TEST CIRCUITS

FIG.12: Test Circuits of Turn On Time

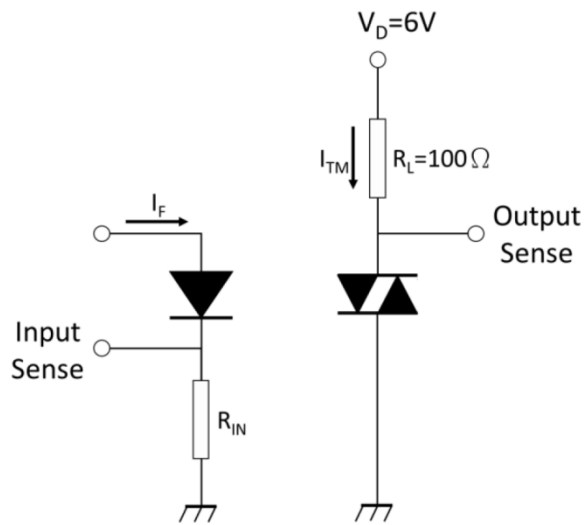


FIG.13: Waveforms of Turn On Time

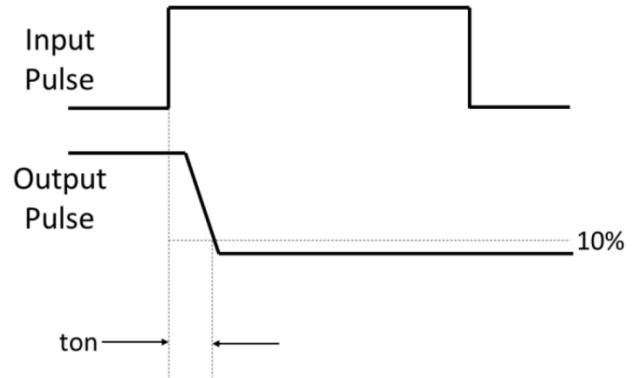


Fig.14: Test Circuits of dV/dt

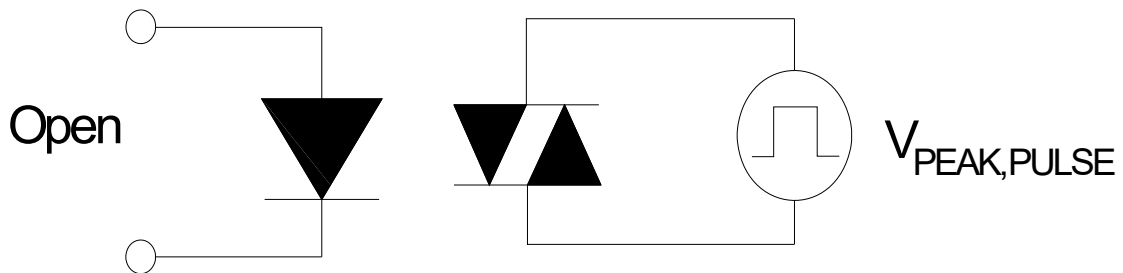


Fig.15: Waveforms of dV/dt

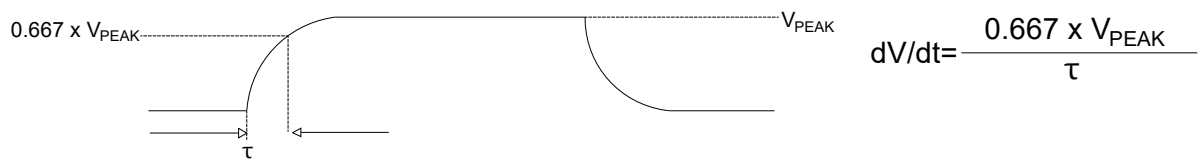
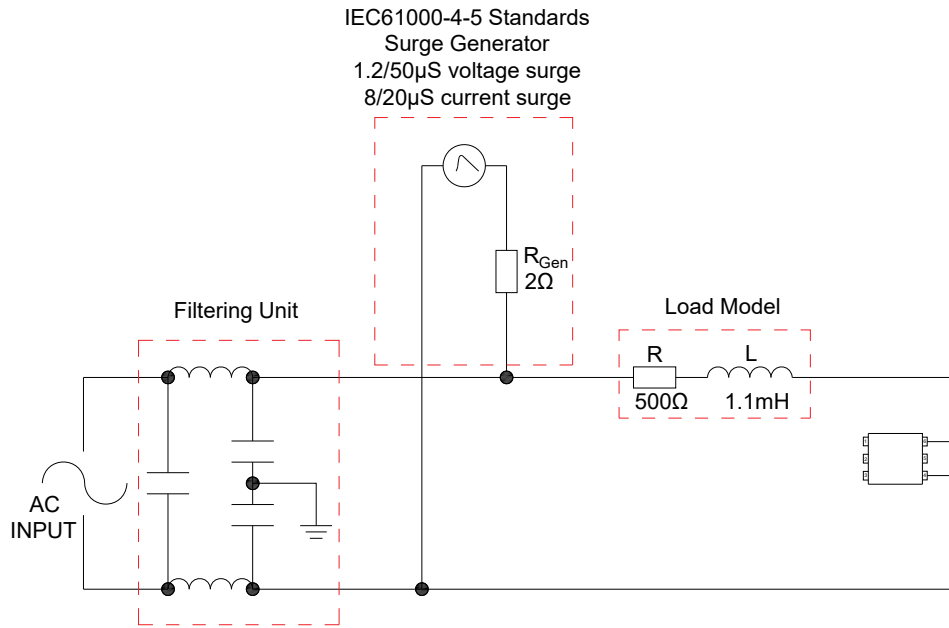
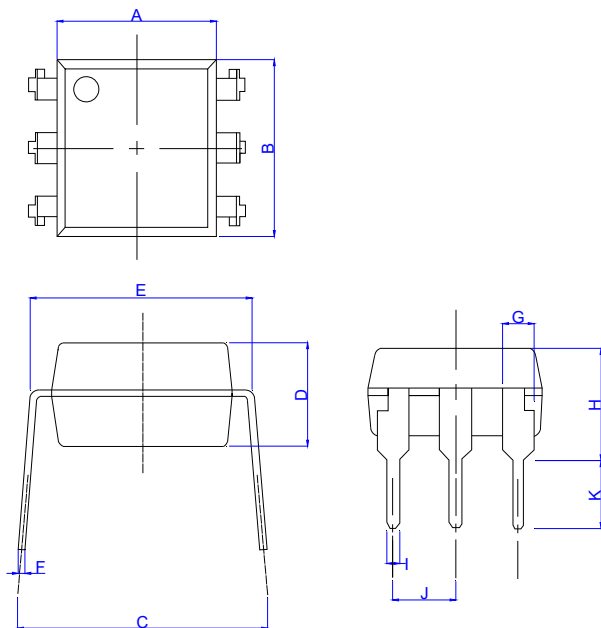


FIG.16: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



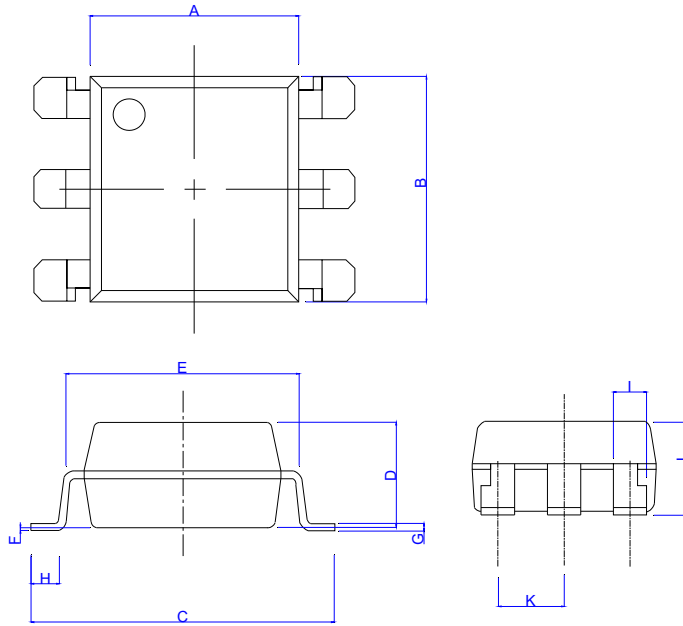
Package Dimension (Unit: mm)

Standard DIP Type:



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	6.20		6.60	0.244		0.260
B	6.92		7.32	0.272		0.288
C	7.15		8.95	0.281		0.352
D	3.20		3.60	0.126		0.142
E	7.32		7.92	0.288		0.312
F	0.15		0.35	0.006		0.014
G	1.15		1.35	0.045		0.053
H	3.90		4.50	0.154		0.177
I	0.40		0.60	0.016		0.024
J	2.29		2.79	0.090		0.110
K	2.24		3.24	0.088		0.128

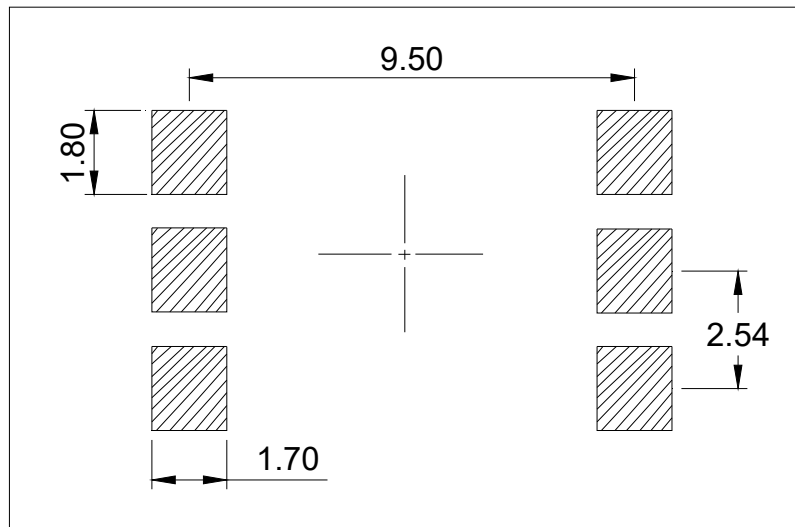
Option SMD Type:



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	6.20		6.60	0.244		0.260
B	6.92		7.32	0.272		0.288
C	9.50		10.50	0.375		0.413
D	3.20		3.60	0.126		0.142
E	7.32		7.92	0.288		0.312
F	0.05		0.35	0.002		0.014
G	0.16		0.36	0.006		0.014
H	0.60		1.40	0.024		0.055
I	0.90		1.50	0.035		0.059
J	3.30		3.90	0.130		0.154
K	2.29		2.79	0.090		0.110

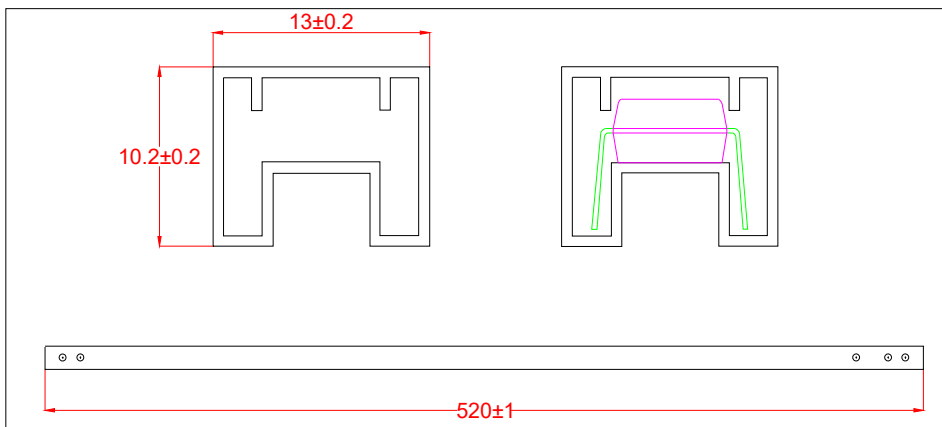
RECOMMENDED SOLDER MASK (Dimensions in mm unless otherwise stated)

Option SMD



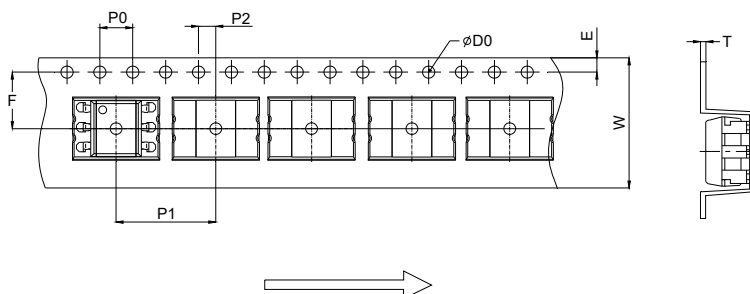
TUBE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Standard DIP



CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option S/L



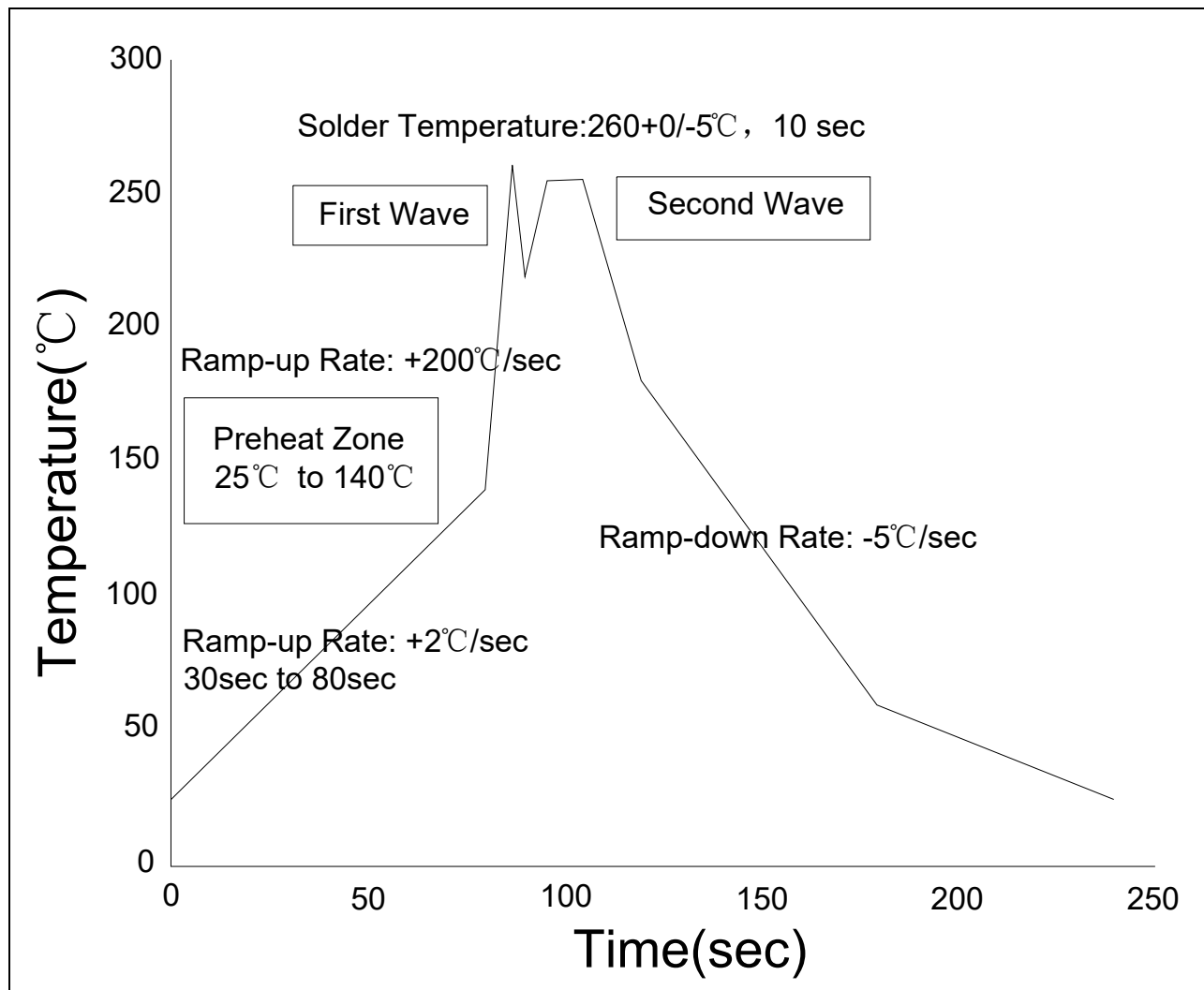
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
D0		1.50	1.60		0.059	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	11.90	12.00	12.10	0.469	0.472	0.476
P2	1.90	2.00	2.10	0.075	0.079	0.083
E	1.65	1.75	1.85	0.065	0.069	0.073
F	7.40	7.50	7.60	0.291	0.295	0.299
T	0.35	0.40	0.45	0.014	0.016	0.018
W	15.70	16.00	16.30	0.618	0.630	0.642

REFLOW INFORMATION



Profile Feature	Sn-Pb Assembly Profile	Pb-Free Assembly Profile
Temperature Min. (T _{smin})	100	150°C
Temperature Max. (T _{smax})	150	200°C
Time (t _s) from (T _{smin} to T _{smax})	60-120 seconds	60-120 seconds
Ramp-up Rate (t _L to t _P)	3°C/second max.	3°C/second max.
Liquidus Temperature (T _L)	183°C	217°C
Time (t _L) Maintained Above (T _L)	60-150 seconds	60-150 seconds
Peak Body Package Temperature	235°C+0°C/-5°C	260°C+0°C/-5°C
Time (t _P) within 5°C of 260°C	20 seconds	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max.	6°C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

WAVE SOLDERING



HAND SOLDERING BY SOLDERING IRON

Soldering Temperature	$360 \pm 5^{\circ}\text{C}$
Soldering Time	3s max.

Note:

1. Reflow soldering is recommended at the temperatures and times shown, no more than three times.
2. Avoid direct contact between the epoxy body and any tools or surfaces exceeding its maximum storage temperature.
3. Application of pressure on the epoxy body is prohibited at elevated temperatures. In specific scenarios, any applied force must not exceed 2.5N.
4. Ensure the component has cooled to ambient temperature before proceeding with any subsequent manufacturing steps.
5. The component has a shelf life of one year when stored under standard conditions.
6. Recommend storage Temp.: 0~40°C;
Recommend storage humidity: <60%;
MSL level: MSL 1

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